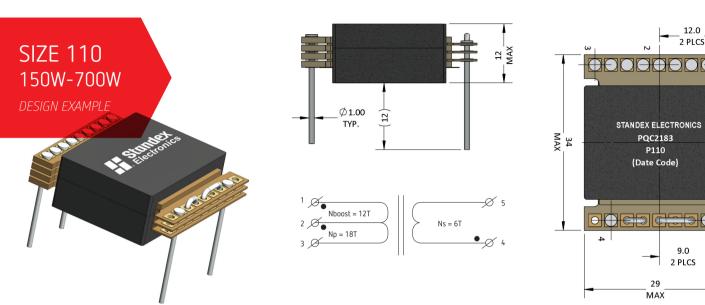
SOLUTIONS | Planar Transformers & Inductors



TRANSFORMER DESIGN | EXAMPLE - PQC2183

Topology	Boost Forward
Input Voltage	120-150VDC
Output Power (Output Voltage/Current After Rectification)	200-300VDC/500-250mA
Output Power (Output Voltage/Current After Rectification) Ns1	0-30VDC/4A
Turns Ratio - Np/Nboost/Ns	18T/12T/6T
Switching Frequency	250kHz
Duty Cycle, Max. At Low Input Voltage	60.0%
Efficiency At Full Power Calculated	98.3% (2.5W losses)
Ambient Temp, Max.	-55°C to +85°C
Mounted On Heatsink With Max. Temp.	+65°C

Temp. Rise, Hotspot Ext. Heatsink, Max.	+25°C
Minimum Isolation Voltage	
Pri. To Secondary Ns1 And To Core	1000VDC
Secondary To Core	500VDC
Primary Inductance, Np, Min.	900µH
Primary Resistance, Rdc, Np, Max.	140m0hm
Secondary Resistance, Rdc, Ns, Max.	18m0hm
Boost Winding Resistance, Rdc, Nboost, Max.	80m0hm
Leakage Inductance 2-3/4-5 Shorted, Typ.	2µH
Weight Range (Approximate)	30-120grams

NOTES:

1) FOR OPTIMAL PERFORMANCE A THERMALLY CONDUCTIVE SUBSTRATE BETWEEN FERRITE & HEATSINK SHOULD BE UTILIZED 2) PATENTED SURFACE MOUNT HEADER AVAILABLE 3) HEATSINK & THERMAL SOLUTIONS AVAILABLE

- 29.0±0.5 - 21.2±0.7